

# Silicon Carbide (SiC) MOSFET

# 28 m $\Omega$ , 1700 V, M1, D2PAK-7L NTBG028N170M1

#### **Features**

- Typ.  $R_{DS(on)} = 28 \text{ m}\Omega$
- Ultra Low Gate Charge (typ. Q<sub>G(tot)</sub> = 222 nC)
- Low Effective Output Capacitance (typ. Coss = 200 pF)
- 100% Avalanche Tested
- RoHS Compliant

#### **Typical Applications**

- UPS
- DC/DC Converter
- Boost Converter

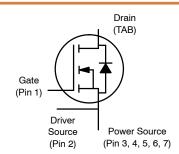
#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V <sub>DSS</sub>	1700	V
Gate-to-Source Voltage			$V_{GS}$	-15/+25	V
	Recommended Operation Values of Gate-to-Source Voltage		$V_{GSop}$	-5/+20	V
Continuous Drain Current (Note 2)	Steady State	T <sub>C</sub> = 25°C	I <sub>D</sub>	71	Α
Power Dissipation (Note 2)			P <sub>D</sub>	428	W
Continuous Drain Current (Note 2)	Steady State T <sub>C</sub> = 100°C		I <sub>D</sub>	53	Α
Power Dissipation (Note 2)			P <sub>D</sub>	214	W
Pulsed Drain Current (Note 3)	T <sub>A</sub> = 25°C		I <sub>DM</sub>	195	Α
Operating Junction and Storage Temperature Range			T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C
Source Current (Body Diode)			IS	99	Α
Single Pulse Drain-to-Source Avalanche Energy (I <sub>L(pk)</sub> = 30 A, L = 1 mH) (Note 4)			E <sub>AS</sub>	450	mJ
Maximum Lead Temperature for Soldering (1/8" from case for 5 s)			TL	300	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Surface mounted on a FR-4 board using1 in2 pad of 2 oz copper.
- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- 3. Repetitive rating, limited by max junction temperature.
- 4. EAS of 450 mJ is based on starting  $T_J$  = 25°C; L = 1 mH,  $I_{AS}$  = 30 A,  $V_{DD}$  = 120 V,  $V_{GS}$  = 18 V.

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX	
1700 V	40 mΩ @ 20 V	71 A	



**N-CHANNEL MOSFET** 



D2PAK-7L CASE 418BJ

#### **MARKING DIAGRAM**

AYWWZZ BG028N 170M1

A = Assembly Location

Y = Year

WW = Work Week

ZZ = Lot Traceability

BG028N170M1 = Specific Device Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTBG028N170M1	D2PAK-7L	800 ea/ Tape&Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Тур	Max	Unit
Junction-to-Case - Steady State (Note 2)	$R_{\theta JC}$	0.35		°C/W
Junction-to-Ambient - Steady State (Notes 1, 2)	$R_{\theta JA}$		40	

#### **ELECTRICAL CHARACTERISTICS** (T<sub>.1</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•						
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 1 mA		1700			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>	I <sub>D</sub> = 1 mA, referenced to 25°C			0.44		V/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		$T_J = 25^{\circ}C$			100	μΑ
		$V_{DS} = 1700 \text{ V}$ $T_{J} = 175^{\circ}\text{C}$				1	mA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = +25/-15 V$ ,	V <sub>DS</sub> = 0 V			±1	μΑ
ON CHARACTERISTICS (Note 3)	-						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D =$	20 mA	1.8	3.0	4.3	V
Recommended Gate Voltage	$V_{GOP}$			-5		+20	V
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 20 V, I <sub>D</sub> = 60 .	A, T <sub>J</sub> = 25°C		28	40	mΩ
		V <sub>GS</sub> = 20 V, I <sub>D</sub> = 60 A	A, T <sub>J</sub> = 175°C		57		
Forward Transconductance	9FS	V <sub>DS</sub> = 20 V, I <sub>D</sub>	= 60 A		27		S
CHARGES, CAPACITANCES & GATE RES	SISTANCE						·
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = 0 V, f = 1 MHz, V <sub>DS</sub> = 800 V			4160		pF
Output Capacitance	C <sub>OSS</sub>				200		
Reverse Transfer Capacitance	C <sub>RSS</sub>				15		
Total Gate Charge	Q <sub>G(TOT)</sub>	$V_{GS} = -5/20 \text{ V}, V_{DS} = 800 \text{ V},$ $I_{D} = 60 \text{ A}$			222		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>				40		
Gate-to-Source Charge	Q <sub>GS</sub>				72		
Gate-to-Drain Charge	$Q_{GD}$				53		
Gate-Resistance	$R_{G}$	f = 1 MHz			6.1		Ω
SWITCHING CHARACTERISTICS	-	-		-	•	•	-
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{GS} = -5/20 \text{ V,}$ $V_{DS} = 1200 \text{ V,}$ $I_D = 60 \text{ A,}$ $R_G = 2 \Omega$ inductive load			47		ns
Rise Time	t <sub>r</sub>				18		
Turn-Off Delay Time	t <sub>d(OFF)</sub>				121		
Fall Time	t <sub>f</sub>				13		
Turn-On Switching Loss	E <sub>ON</sub>				1311		μJ
Turn-Off Switching Loss	E <sub>OFF</sub>				683		
Total Switching Loss	E <sub>tot</sub>				1994		
DRAIN-SOURCE DIODE CHARACTERIST	rics						
Continuous Drain-Source Diode Forward Current	I <sub>SD</sub>	$V_{GS} = -5 \text{ V}, T_J = 25^{\circ}\text{C}$				99	Α
Pulsed Drain-Source Diode Forward Current (Note 3)	I <sub>SDM</sub>					195	
Forward Diode Voltage	$V_{SD}$	V <sub>GS</sub> = -5 V, I <sub>SD</sub> = 60 A, T <sub>J</sub> = 25°C			4.3		V
Reverse Recovery Time	t <sub>RR</sub>	V <sub>GS</sub> = -5/20 V, I <sub>SD</sub> = 60 A, dI <sub>S</sub> /dt = 1000 A/μs			33		ns
Reverse Recovery Charge	Q <sub>RR</sub>				247		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **TYPICAL CHARACTERISTICS**

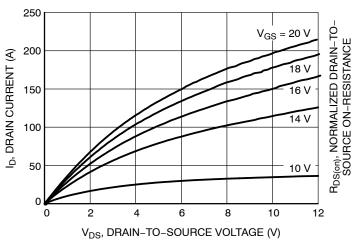


Figure 1. On-Region Characteristics

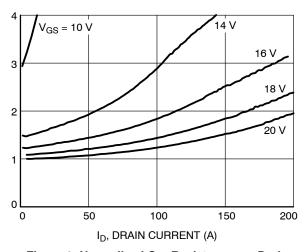


Figure 2. Normalized On-Resistance vs. Drain Current and Gate Voltage

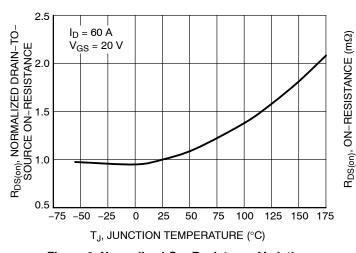


Figure 3. Normalized On-Resistance Variation with Temperature

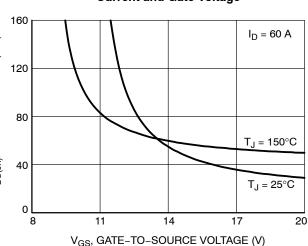


Figure 4. On-Resistance vs. Gate-to-Source Voltage

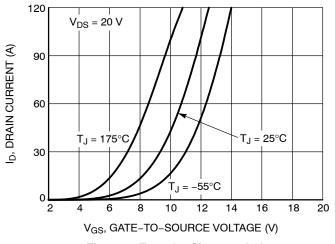


Figure 5. Transfer Characteristics

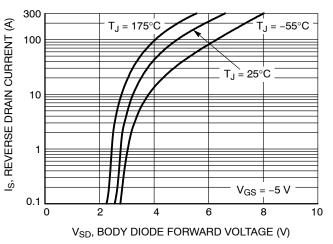
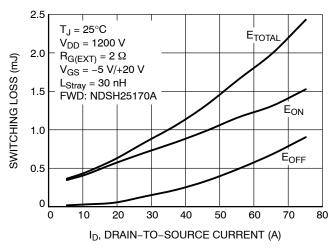


Figure 6. Diode Forward Voltage vs. Current

#### **TYPICAL CHARACTERISTICS**



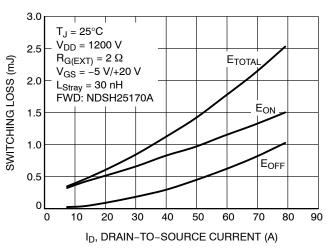


Figure 7. SW Loss vs. ID 25°C

Figure 8. SW Loss vs. ID 125°C

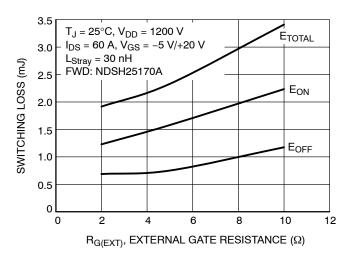


Figure 9. SW Loss vs. Rg

#### TYPICAL CHARACTERISTICS

10K

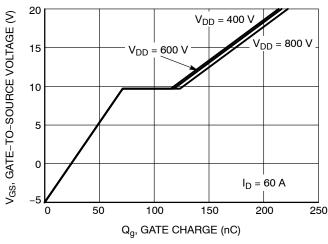
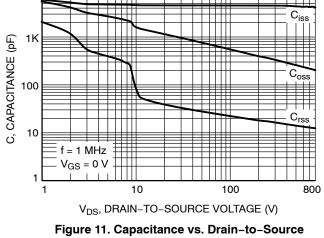


Figure 10. Gate-to-Source Voltage vs. Total Charge



Voltage

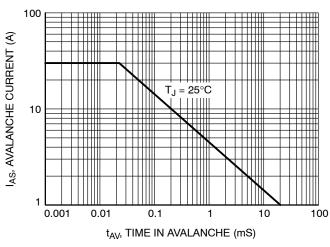


Figure 12. Unclamped Inductive Switching Capability

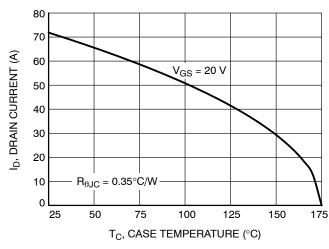


Figure 13. Maximum Continuous Drain **Current vs. Case Temperature** 

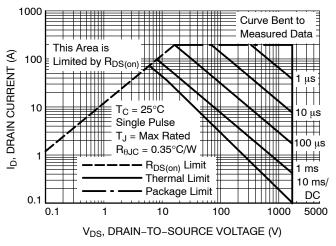


Figure 14. Maximum Rated Forward Biased Safe Operating Area

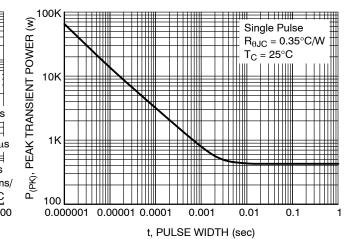


Figure 15. Single Pulse Maximum Power Dissipation

### **TYPICAL CHARACTERISTICS**

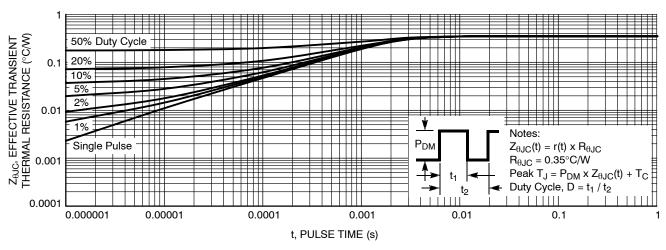
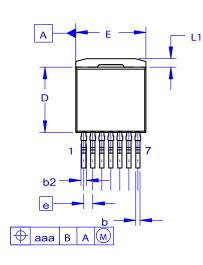
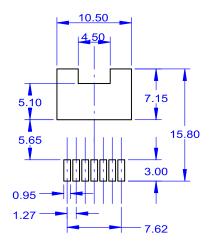


Figure 16. Transient Thermal Impedance

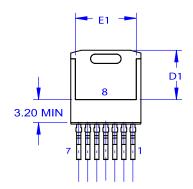
#### **PACKAGE DIMENSIONS**

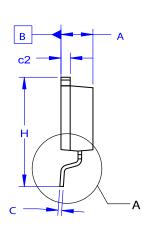
# D<sup>2</sup>PAK7 (TO-263-7L HV) CASE 418BJ ISSUE A





LAND PATTERN RECOMMENDATION





#### NOTES:

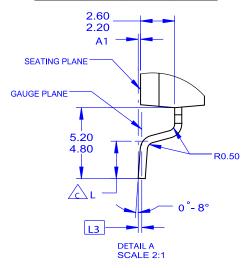
A. PACKAGE CONFORMS TO JEDEC TO-263 VARIATION CB EXCEPT WHERE NOTED. B. ALL DIMENSIONS ARE IN MILLIMETERS.

OUT OF JEDEC STANDARD VALUE.

D. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.

E. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.

MILLIMETERS           MIN         NOM         MAX           A         4.30         4.50         4.70           A1         0.00         0.10         0.20           b2         0.60         0.70         0.80           b         0.51         0.60         0.70           c         0.40         0.50         0.60           c2         1.20         1.30         1.40           D         9.00         9.20         9.40           D1         6.75         6.95         7.15           E         9.70         9.90         10.20           E1         7.70         7.90         8.10           e         ~         1.27         ~           H         15.10         15.40         15.70           L         2.44         2.64         2.84           L1         1.00         1.20         1.40           L3         ~         0.25         ~           aaa         ~         0.25         ~						
MIN         NOM         MAX           A         4.30         4.50         4.70           A1         0.00         0.10         0.20           b2         0.60         0.70         0.80           b         0.51         0.60         0.70           c         0.40         0.50         0.60           c2         1.20         1.30         1.40           D         9.00         9.20         9.40           D1         6.75         6.95         7.15           E         9.70         9.90         10.20           E1         7.70         7.90         8.10           e         ~         1.27         ~           H         15.10         15.40         15.70           L         2.44         2.64         2.84           L1         1.00         1.20         1.40           L3         ~         0.25         ~	DIM	MILLIMETERS				
A1         0.00         0.10         0.20           b2         0.60         0.70         0.80           b         0.51         0.60         0.70           c         0.40         0.50         0.60           c2         1.20         1.30         1.40           D         9.00         9.20         9.40           D1         6.75         6.95         7.15           E         9.70         9.90         10.20           E1         7.70         7.90         8.10           e         ~         1.27         ~           H         15.10         15.40         15.70           L         2.44         2.64         2.84           L1         1.00         1.20         1.40           L3         ~         0.25         ~	DIM	MIN	NOM	MAX		
b2         0.60         0.70         0.80           b         0.51         0.60         0.70           c         0.40         0.50         0.60           c2         1.20         1.30         1.40           D         9.00         9.20         9.40           D1         6.75         6.95         7.15           E         9.70         9.90         10.20           E1         7.70         7.90         8.10           e         ~         1.27         ~           H         15.10         15.40         15.70           L         2.44         2.64         2.84           L1         1.00         1.20         1.40           L3         ~         0.25         ~	Α	4.30	4.50	4.70		
b         0.51         0.60         0.70           c         0.40         0.50         0.60           c2         1.20         1.30         1.40           D         9.00         9.20         9.40           D1         6.75         6.95         7.15           E         9.70         9.90         10.20           E1         7.70         7.90         8.10           e         ~         1.27         ~           H         15.10         15.40         15.70           L         2.44         2.64         2.84           L1         1.00         1.20         1.40           L3         ~         0.25         ~	A1	0.00	0.10	0.20		
c     0.40     0.50     0.60       c2     1.20     1.30     1.40       D     9.00     9.20     9.40       D1     6.75     6.95     7.15       E     9.70     9.90     10.20       E1     7.70     7.90     8.10       e     ~     1.27     ~       H     15.10     15.40     15.70       L     2.44     2.64     2.84       L1     1.00     1.20     1.40       L3     ~     0.25     ~	b2	0.60	0.70	0.80		
c2       1.20       1.30       1.40         D       9.00       9.20       9.40         D1       6.75       6.95       7.15         E       9.70       9.90       10.20         E1       7.70       7.90       8.10         e       ~       1.27       ~         H       15.10       15.40       15.70         L       2.44       2.64       2.84         L1       1.00       1.20       1.40         L3       ~       0.25       ~	b	0.51	0.60	0.70		
D       9.00       9.20       9.40         D1       6.75       6.95       7.15         E       9.70       9.90       10.20         E1       7.70       7.90       8.10         e       ~       1.27       ~         H       15.10       15.40       15.70         L       2.44       2.64       2.84         L1       1.00       1.20       1.40         L3       ~       0.25       ~	C	0.40	0.50	0.60		
D1       6.75       6.95       7.15         E       9.70       9.90       10.20         E1       7.70       7.90       8.10         e       ~       1.27       ~         H       15.10       15.40       15.70         L       2.44       2.64       2.84         L1       1.00       1.20       1.40         L3       ~       0.25       ~	c2	1.20	1.30	1.40		
E 9.70 9.90 10.20 E1 7.70 7.90 8.10 e ~ 1.27 ~ H 15.10 15.40 15.70 L 2.44 2.64 2.84 L1 1.00 1.20 1.40 L3 ~ 0.25 ~	D	9.00	9.20	9.40		
E1 7.70 7.90 8.10  e ~ 1.27 ~  H 15.10 15.40 15.70  L 2.44 2.64 2.84  L1 1.00 1.20 1.40  L3 ~ 0.25 ~	D1	6.75	6.95	7.15		
e ~ 1.27 ~ H 15.10 15.40 15.70 L 2.44 2.64 2.84 L1 1.00 1.20 1.40 L3 ~ 0.25 ~	Е	9.70	9.90	10.20		
H 15.10 15.40 15.70 L 2.44 2.64 2.84 L1 1.00 1.20 1.40 L3 ~ 0.25 ~	E1	7.70	7.90	8.10		
L 2.44 2.64 2.84 L1 1.00 1.20 1.40 L3 ~ 0.25 ~	е	~	1.27	~		
L1 1.00 1.20 1.40 L3 ~ 0.25 ~	Η	15.10	15.40	15.70		
L3 ~ 0.25 ~	L	2.44	2.64	2.84		
	L1	1.00	1.20	1.40		
aaa ~ ~ 0.25	L3	~	0.25	~		
	aaa	~	~	0.25		



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